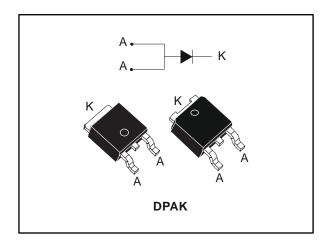
FERD2045S



45 V field-effect rectifier diode

Datasheet - production data



Features

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation
- ECOPACK®2 compliant component for DPAK on demand

Description

This single rectifier is based on a proprietary technology that achieves the best in class V_F/I_R trade-off for a given silicon surface.

Therefore it can advantageously replace 45 V low voltage Schottky diodes.

Packaged in DPAK, this device is intended to be used in rectification and freewheeling operations in power supplies.

Table 1: Device summary

Symbol	Value
I _{F(AV)}	20 A
V _{RRM}	45 V
V _F (typ.)	0.29 V
T _i (max.)	150 °C

Characteristics FERD2045S

1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short-circuited)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	45	V	
I _{F(RMS)}	Forward rms current	40	Α	
I _{F(AV)}	Average forward current δ = 0.5, square wave	T _C = 125 °C	20	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		180	Α
T _{stg}	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperature	-40 to +150	°C	

Notes:

Table 3: Thermal resistance parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	1.4	°C/W

Table 4: Static electrical characteristics (anode terminals short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Down look and the second	T _j = 25 °C	V _R = 35 V	-	100	300	μΑ
		T _j = 125 °C		-	12	24	mA
IR ^(*)	Reverse leakage current	T _j = 25 °C	\/- \/	-	200	600	μΑ
		T _j = 125 °C	$V_R = V_{RRM}$	-	18	40	mΑ
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 5 A	-	0.35		V
		T _j = 125 °C		-	0.29		
		T _j = 25 °C	I _F = 10 A	-	0.41	0.45	
		T _j = 125 °C		-	0.38	0.42	
		T _j = 25 °C	I _F = 20 A	-	0.51	0.55	
		T _j = 125 °C		-	0.52	0.57	

Notes:

To evaluate the maximum conduction losses use the following equation:

$$P = 0.27 \text{ x } I_{F(AV)} + 0.015 \text{ x } I_{F^2(RMS)}$$

 $^{^{(1)}(}dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

 $^{^{(1)}\}text{Pulse}$ test: t_p = 5 ms, δ < 2%

 $^{^{(2)}}$ Pulse test: t_p = 380 μ s, δ < 2%

FERD2045S Characteristics

Characteristics (curves) 1.1

15

10

0

25

50

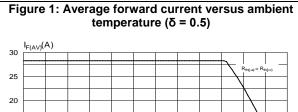


Figure 2: Relative variation of thermal impedance junction to case versus pulse duration $Z_{th(j-c)}/R_{th(j-c)}$ 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 t_p(s) 0.0 1.E-04 1.E-03 1.E-02 1.E+00 1.E-01

Figure 3: Reverse leakage current versus reverse voltage applied (typical values) $I_R(mA)$ 1.E+02

 $T_{amb}(^{\circ}C)$

75

100

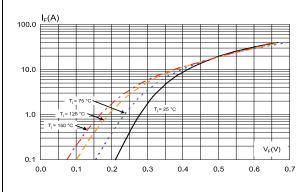
125

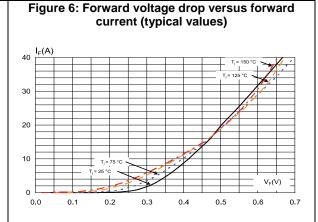
150

1.E+01 1.E+00 1.E-01 1.E-02 10 15 20 25 40 45

Figure 4: Junction capacitance versus reverse voltage applied (typical values) C(pF) 10000 1000 $V_R(V)$ 100 10

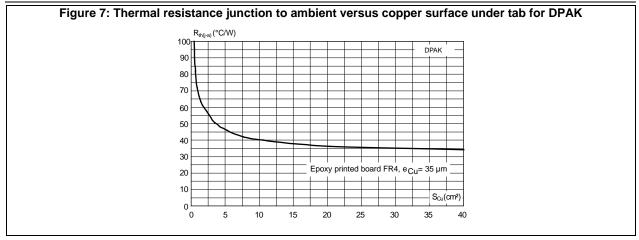
Figure 5: Forward voltage drop versus forward current (typical values)







Characteristics FERD2045S



FERD2045S Package information

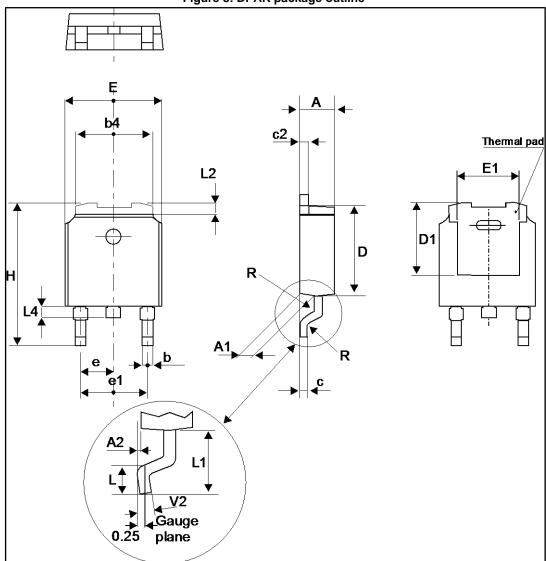
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0

2.1 DPAK package information

Figure 8: DPAK package outline





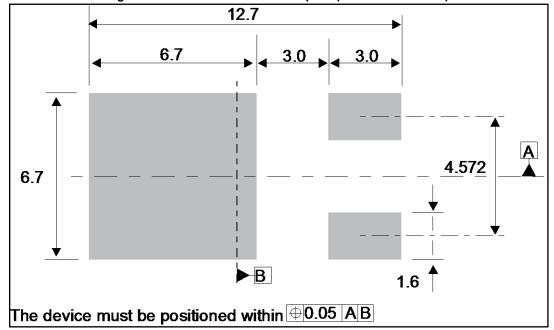
This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.



Table 5: DPAK package mechanical data

	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
А	2.18	2.40	0.085	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
b	0.64	0.90	0.025	0.035	
b4	4.95	5.46	0.194	0.215	
С	0.46	0.61	0.018	0.024	
c2	0.46	0.60	0.018	0.023	
D	5.97	6.22	0.235	0.244	
D1	4.95	5.60	0.194	0.220	
Е	6.35	6.73	0.250	0.265	
E1	4.32	5.50	0.170	0.216	
е	2.2	86 typ.	0.090) typ.	
e1	4.40	4.70	0.173	0.185	
Н	9.35	10.40	0.368	0.409	
L	1.0	1.78	0.039	0.070	
L2		1.27		0.050	
L4	0.60	1.02	0.023	0.040	
V2	-8°	+8°	-8°	+8°	

Figure 9: DPAK recommended footprint (dimensions in mm)



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FERD2045S Ordering information

3 Ordering information

Table 6: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD2045SB-TR	FERD 2045	DPAK	0.32 g	2500	Tape and reel

4 Revision history

Table 7: Document revision history

Date	Revision	Changes
15-Jan-2018	1	Initial release.



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